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Complete if Known

Substitute for form 1449B/PTO

INFORMATION DISCLOSURE
STATEMENT BY APPLICANT

Date Submitted: February 7, 2005

(use as many sheets as necessary)

Sheet

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of

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Application Number	10/620,194
Filing Date	07/15/2003
First Named Inventor	Eric N. Paton
Group Art Unit	2823
Examiner Name	Joannie A. Garcia
Attorney Docket Number	039153-0646 (H0975)

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (if known)			
JAG	A1	2004/0089914	A1	Mouli et al.	05-13-2004	
JAG	A2	2004/0061161	A1	Radens et al.	04-01-2004	
JAG	A3	6,673,696	B1	Arasnia et al.	01-06-2004	
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Examiner Initials*	Cite No. ¹	Foreign Patent Document			Name of Patentee or Applicant of Cited Documents	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		Office ³	Number ⁴	Kind Code ⁵ (if known)				
JAG	A15	WO	02/101818	A2	Currie et al.	12/19/2002		
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NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ⁶
JAG	A19	Written Opinion of the International Searching Authority; International Application No. PCT/US2004/007464; International Filing Date 03-11-2004; 6 pgs.	

Examiner Signature

Joannie A. Garcia

Date Considered

April 13, 2005

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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Sheet	2	of	2
		Attorney Docket Number	039153-0646 (H0975)

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ⁶
JAG	A20	International Search Report; International Application No. PCT/US2004/007464; mailed 01/09/2004; 3 pgs.	
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JAG	A27	VOSSSEN, John L. and KERN, Werner, "Thin Film Processes II, Academic Press, 1991, page 333	
JAG	A28	RIM, K., WELSER, J., HOYT, J.L., and GIBBONS, J.F., "Enhanced Hole Mobilities in Surface-channel Strained-Si p-MOSFETs", 1995 International Electron Devices Meeting TECHNICAL DIGEST, 5 pages.	
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Examiner Signature	<i>Joannie A. Garcia</i>	Date Considered	<i>April 13 2005</i>
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